



**DRAM** (接上页) - 由于市场波动, 请参考 **Digi-Key** 网站来获取最新定价信息。

Micron Technology 零件编号	Digi-Key 零件编号	说明	封装	单价★		
				1	25	100
MT47H32M16BN-5E-D TR	557-1214-1-ND	DDR2 SDRAM, 512Mb	DDR2 SDRAM, 512Mb	84-FBGA	10.70	8.04 7.38
MT47H32M16BN-5E-D TR	557-1214-2-ND	DDR2 SDRAM, 512Mb	DDR2 SDRAM, 512Mb	84-FBGA		6749.00/1,000
MT47H64M48B-37E-B TR	557-1290-1-ND	DDR2 SDRAM, 256Mb	DDR2 SDRAM, 256Mb	60-FBGA	11.96	8.98 8.25
MT47H64M48B-37E-B TR	557-1290-2-ND	DDR2 SDRAM, 256Mb	DDR2 SDRAM, 256Mb	60-FBGA		7543.00/1,000
MT47H64M8B6-3-D TR	557-1215-1-ND	DDR2 SDRAM, 512Mb	DDR2 SDRAM, 512Mb	60-FBGA	10.34	7.77 7.13
MT47H64M8B6-3-D TR	557-1215-2-ND	DDR2 SDRAM, 512Mb	DDR2 SDRAM, 512Mb	60-FBGA		6520.00/1,000
MT47H64M16HR-3-E TR	557-1341-1-ND	DDR2 SDRAM, 1Gb	DDR2 SDRAM, 1Gb	84-FBGA	21.07	16.41 15.41
MT47H64M16HR-3-E TR	557-1341-2-ND	DDR2 SDRAM, 1Gb	DDR2 SDRAM, 1Gb	84-FBGA		2834.00/2,000
MT47H128M48B-3-D TR	557-1291-1-ND	DDR2 SDRAM, 512Mb	DDR2 SDRAM, 512Mb	60-FBGA	14.69	11.03 10.13
MT47H128M48B-3-D TR	557-1291-2-ND	DDR2 SDRAM, 512Mb	DDR2 SDRAM, 512Mb	60-FBGA		9263.00/1,000
MT47H128M48T-37E-A TR	557-1044-1-ND	DDR2 SDRAM, 512Mb	DDR2 SDRAM, 512Mb	92-FBGA	30.42	23.40 21.84
MT47H128M8HQ-3-E TR	557-1339-1-ND	DDR2 SDRAM, 1Gb	DDR2 SDRAM, 1Gb	60-FBGA	19.25	14.99 14.08
MT47H128M8HQ-3-E TR	557-1339-2-ND	DDR2 SDRAM, 1Gb	DDR2 SDRAM, 1Gb	60-FBGA		12949.00/1,000
MT47H256M48T-5E-A TR	557-1206-1-ND	DDR2 SDRAM, 1Gb	DDR2 SDRAM, 1Gb	92-FBGA	52.67	41.50 39.90
MT47H256M48T-5E-A TR	557-1206-2-ND	DDR2 SDRAM, 1Gb	DDR2 SDRAM, 1Gb	92-FBGA		35623.00/1,000
MT47H256M4HQ-3-E TR	557-1340-1-ND	DDR2 SDRAM, 1Gb	DDR2 SDRAM, 1Gb	60-FBGA	29.21	22.74 21.36
MT47H256M4HQ-3-E TR	557-1340-2-ND	DDR2 SDRAM, 1Gb	DDR2 SDRAM, 1Gb	60-FBGA		2014.00/1,000
MT47H256M4HQ-5E-E TR	557-1207-1-ND	DDR2 SDRAM, 1Gb	DDR2 SDRAM, 1Gb	60-FBGA	34.30	25.27 23.47
MT47H256M4HQ-5E-E TR	557-1207-2-ND	DDR2 SDRAM, 1Gb	DDR2 SDRAM, 1Gb	60-FBGA		20577.00/1,000



**闪存** - 符合 RoHS 的规范要求

Micron Technology 零件编号	Digi-Key 零件编号	说明	封装	单价★		
				1	25	100
与非闪存						
MT29F2G08AACWP-C TR	557-1201-1-ND	2Gb, 3.3V	2Gb, 3.3V	48-TSOP	10.06	6.81 6.46
MT29F2G08AACWP-C TR	557-1201-2-ND	2Gb, 3.3V	2Gb, 3.3V	48-TSOP		5857.00/1,000
MT29F4G16BABWP	557-1154-1-ND	4Gb, 3.3V	4Gb, 3.3V	48-TSOP	47.03	37.05 35.63



**PSRAM** - 符合 RoHS 的规范要求

Micron Technology 零件编号	Digi-Key 零件编号	说明	封装	单价★		
				1	25	100
MT45W1MW168AB8-706 WT TR	557-1006-1-ND	异步/分页/突发 CellularRAM™, 16Mb	Async./Page/Burst CellularRAM™, 16Mb	54-VFBGA	5.04	3.48 3.20
MT45W1MW168AB8-706 WT TR	557-1006-2-ND	异步/分页/突发 CellularRAM™, 16Mb	Async./Page/Burst CellularRAM™, 16Mb	54-VFBGA		2940.00/1,000
MT45W1MW1680B8-701 WT TR	557-1209-1-ND	异步/分页/突发 CellularRAM™, 16Mb	Async./Page/Burst CellularRAM™, 16Mb	54-VFBGA	4.53	2.88 2.60
MT45W1MW1680B8-701 WT TR	557-1209-2-ND	异步/分页/突发 CellularRAM™, 16Mb	Async./Page/Burst CellularRAM™, 16Mb	54-VFBGA		2311.00/1,000
MT45W1MW1680B8-708 WT TR	557-1274-1-ND	异步/分页/突发 CellularRAM™, 16Mb	Async./Page/Burst CellularRAM™, 16Mb	54-VFBGA	3.33	2.12 1.91
MT45W1MW1680B8-708 WT TR	557-1274-2-ND	异步/分页/突发 CellularRAM™, 16Mb	Async./Page/Burst CellularRAM™, 16Mb	54-VFBGA		1698.00/1,000
MT45W1MW16PDGA-70 WT TR	557-1275-1-ND	异步/分页 CellularRAM™, 16Mb	Async./Page CellularRAM™, 16Mb	48-VFBGA	3.33	2.12 1.91
MT45W1MW16PDGA-70 WT TR	557-1275-2-ND	异步/分页 CellularRAM™, 16Mb	Async./Page CellularRAM™, 16Mb	48-VFBGA		1698.00/1,000
MT45W2MW168AB8-706 WT TR	557-1007-1-ND	异步/分页/突发 CellularRAM™, 32Mb	Async./Page/Burst CellularRAM™, 32Mb	54-VFBGA	5.99	4.14 3.80
MT45W2MW168AB8-706 WT TR	557-1007-2-ND	异步/分页/突发 CellularRAM™, 32Mb	Async./Page/Burst CellularRAM™, 32Mb	54-VFBGA		5.70 3.43 3.27
MT45W2MW1680B8-708 WT TR	557-1318-2-ND	异步/分页/突发 CellularRAM™, 32Mb	Async./Page/Burst CellularRAM™, 32Mb	54-VFBGA		2912.00/1,000
MT45W2MW1680B8-708 WT TR	557-1317-1-ND	异步/分页 CellularRAM™, 32Mb	Async./Page CellularRAM™, 32Mb	48-VFBGA	6.18	3.71 3.54
MT45W2MW1680B8-708 WT TR	557-1317-2-ND	异步/分页 CellularRAM™, 32Mb	Async./Page CellularRAM™, 32Mb	48-VFBGA		3154.00/1,000
MT45W2MW1680B8-708 WT TR	557-1316-1-ND	异步/分页 CellularRAM™, 32Mb	Async./Page CellularRAM™, 32Mb	48-VFBGA	5.70	3.43 3.27
MT45W2MW1680B8-708 WT TR	557-1316-2-ND	异步/分页 CellularRAM™, 32Mb	Async./Page CellularRAM™, 32Mb	48-VFBGA		2912.00/1,000
MT45W4MW1688B-706 WT TR	557-1008-1-ND	异步/分页/突发 CellularRAM™, 64Mb	Async./Page/Burst CellularRAM™, 64Mb	54-VFBGA	4.57	3.84 3.62
MT45W4MW1688B-706 WT TR	557-1172-1-ND	异步/分页/突发 CellularRAM™, 1.0 存储器	Async./Page/Burst CellularRAM™, 1.0 Memory	54-VFBGA	6.84	4.86 4.40
MT45W4MW1688B-706 WT TR	557-1172-2-ND	异步/分页/突发 CellularRAM™, 1.0 存储器	Async./Page/Burst CellularRAM™, 1.0 Memory	54-VFBGA		3983.00/1,000
MT45W4MW1688B-706 WT TR	557-1210-1-ND	异步/分页 CellularRAM™, 64Mb	Async./Page CellularRAM™, 64Mb	48-VFBGA	6.84	4.86 4.40
MT45W4MW1688B-706 WT TR	557-1210-2-ND	异步/分页 CellularRAM™, 64Mb	Async./Page CellularRAM™, 64Mb	48-VFBGA		3983.00/1,000
MT45W8MW1688B-708 WT TR	557-1010-1-ND	异步/分页/突发 CellularRAM™, 128Mb	Async./Page/Burst CellularRAM™, 128Mb	54-VFBGA	9.36	6.33 6.02
MT45W8MW1688B-708 WT TR	557-1010-2-ND	异步/分页/突发 CellularRAM™, 128Mb	Async./Page/Burst CellularRAM™, 128Mb	54-VFBGA		5450.00/1,000



**SDRAM** - 符合 RoHS 规范要求 - 由于市场波动, 请参考 **Digi-Key** 网站来获取最新定价信息。

Qimonda 零件编号	Digi-Key 零件编号	说明	封装	单价★		
				1	25	100
HYB39S128160FE-7	675-1002-1-ND	128Mb SDRAM	128Mb SDRAM	54-TSOP	5.30	3.76 3.40
HYB39S128160FE-7	675-1002-2-ND	128Mb SDRAM	128Mb SDRAM	54-TSOP		4624.50/1,500
HYB39S128800FE-7	675-1001-1-ND	128Mb SDRAM	128Mb SDRAM	54-TSOP	5.30	3.76 3.40
HYB39S128800FE-7	675-1001-2-ND	128Mb SDRAM	128Mb SDRAM	54-TSOP		4624.50/1,500
HYB39S256160FE-7	675-1004-1-ND	256Mb SDRAM	256Mb SDRAM	54-TSOP	6.78	4.81 4.36
HYB39S256160FE-7	675-1004-2-ND	256Mb SDRAM	256Mb SDRAM	54-TSOP		5919.00/1,500
HYB39S256800FE-7	675-1003-1-ND	256Mb SDRAM	256Mb SDRAM	54-TSOP	6.78	4.81 4.36
HYB39S256800FE-7	675-1003-2-ND	256Mb SDRAM	256Mb SDRAM	54-TSOP		5919.00/1,500
HYI39S128160FE-7	675-1019-1-ND	128Mb SDRAM	128Mb SDRAM	54-TSOP	6.35	4.51 4.08
HYI39S128160FE-7	675-1019-2-ND	128Mb SDRAM	128Mb SDRAM	54-TSOP		5548.50/1,500
HYI39S128800FE-7	675-1020-1-ND	128Mb SDRAM	128Mb SDRAM	54-TSOP	6.35	4.51 4.08
HYI39S128800FE-7	675-1020-2-ND	128Mb SDRAM	128Mb SDRAM	54-TSOP		5548.50/1,500
<b>DDR</b>						
HYB25D128800CE-6	675-1005-1-ND	128Mb DDR SDRAM	128Mb DDR SDRAM	66-TSOP	5.88	3.53 3.37
HYB25D128800CE-6	675-1005-2-ND	128Mb DDR SDRAM	128Mb DDR SDRAM	66-TSOP		4347.00/1,500
HYB25D256160CE-5	675-1006-1-ND	256Mb DDR SDRAM	256Mb DDR SDRAM	66-TFBGA	6.35	4.51 4.08
HYB25D256160CE-5	675-1006-2-ND	256Mb DDR SDRAM	256Mb DDR SDRAM	66-TFBGA		5548.50/1,500
HYB25D256160CF-5	675-1007-1-ND	256Mb DDR SDRAM	256Mb DDR SDRAM	60-TFBGA	6.35	4.51 4.08
HYB25D256160CF-5	675-1007-2-ND	256Mb DDR SDRAM	256Mb DDR SDRAM	60-TFBGA		7200.00/2,000
HYB25D512160CE-5	675-1010-1-ND	512Mb DDR SDRAM	512Mb DDR SDRAM	66-TSOP	11.64	8.74 8.03
HYB25D512160CE-5	675-1010-2-ND	512Mb DDR SDRAM	512Mb DDR SDRAM	66-TSOP		10980.00/1,500
HYB25D512800CE-5	675-1009-1-ND	512Mb DDR SDRAM	512Mb DDR SDRAM	66-TSOP	11.64	8.74 8.03
HYB25D512800CE-5	675-1009-2-ND	512Mb DDR SDRAM	512Mb DDR SDRAM	66-TSOP		10980.00/1,500
HYB25D512800CE-6	675-1008-1-ND	512Mb DDR SDRAM	512Mb DDR SDRAM	66-TSOP	11.64	8.74 8.03
HYB25D512800CE-6	675-1008-2-ND	512Mb DDR SDRAM	512Mb DDR SDRAM	66-TSOP		10980.00/1,500
HYI25D256160CE-5	675-1021-1-ND	256Mb DDR SDRAM	256Mb DDR SDRAM	66-TSOP	7.41	5.26 4.76
HYI25D256160CE-5	675-1021-2-ND	256Mb DDR SDRAM	256Mb DDR SDRAM	66-TSOP		6300.00/1,500
HYI25D512160CE-5	675-1022-1-ND	512Mb DDR SDRAM	512Mb DDR SDRAM	66-TSOP	13.36	10.03 9.21
HYI25D512160CE-5	675-1022-2-ND	512Mb DDR SDRAM	512Mb DDR SDRAM	66-TSOP		12600.00/1,500
<b>DDR2</b>						
HYB18T1G160BF-5	675-1018-1-ND	1Gb DDR2 SDRAM	1Gb DDR2 SDRAM	84-TFBGA	47.70	39.45 36.99
HYB18T1G160BF-5	675-1018-2-ND	1Gb DDR2 SDRAM	1Gb DDR2 SDRAM	84-TFBGA		7200.00/2,000
HYB18T1G800BF-3S	675-1017-1-ND	1Gb DDR2 SDRAM	1Gb DDR2 SDRAM	68-TFBGA	47.70	39.45 36.99
HYB18T1G800BF-3S	675-1017-2-ND	1Gb DDR2 SDRAM	1Gb DDR2 SDRAM	68-TFBGA		7200.00/2,000
HYB18T512160BF-2.5	675-1016-1-ND	512Mb DDR2 SDRAM	512Mb DDR2 SDRAM	84-TFBGA	17.17	12.89 11.84

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1258 (CN082-09)

digikey.com.cn — 电话: (852) 3104 0500 — 传真: (852) 3104 0686

Qimonda 零件编号	Digi-Key 零件编号	说明	封装	单价★
HYB18T512160BF-2.5	675-1016-2-ND	512Mb DDR2 SDRAM	84-TFBGA	1 25 100
HYB18T512160BF-3.7	675-1014-1-ND	512Mb DDR2 SDRAM	84-TFBGA	12.02 9.03 8.29
HYB18T512160BF-3.7	675-1014-2-ND	512Mb DDR2 SDRAM	84-TFBGA	15120.00/2,000
HYB18T512160BF-3S	675-1015-1-ND	512Mb DDR2 SDRAM	84-TFBGA	7.41 5.26 4.76
HYB18T512160BF-3S	675-1015-2-ND	512Mb DDR2 SDRAM	84-TFBGA	8400.00/2,000
HYB18T512800BF-2.5	675-1013-1-ND	512Mb DDR2 SDRAM	60-TFBGA	17.17 12.89 11.84
HYB18T512800BF-2.5	675-1013-2-ND	512Mb DDR2 SDRAM	60-TFBGA	21600.00/2,000
HYB18T512800BF-3.7	675-1011-1-ND	512Mb DDR2 SDRAM	60-TFBGA	12.02 9.03 8.29
HYB18T512800BF-3.7	675-1011-2-ND	512Mb DDR2 SDRAM	60-TFBGA	15120.00/2,000
HYB18T512800BF-3S	675-1012-1-ND	512Mb DDR2 SDRAM	60-TFBGA	12.40 9.31 8.55
HYB18T512800BF-3S	675-1012-2-ND	512Mb DDR2 SDRAM	60-TFBGA	15600.00/2,000

存储器

提供符合 RoHS 规范要求的零件

Digi-Key 零件编号	说明	封装	单价★
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闪存

Toshiba - 符合 RoHS 规范要求

TC58FVM6B5BTG65-ND	64MB 3V 或非 CMOS (8Mx8/4Mx16) 底部启动块	64M-Bit 3V NOR CMOS (8Mx8/4Mx16) Bottom Boot Block	48-TSOP	8.00 6.40 5.40
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SRAM

Toshiba

TC55VEM416AXGN55-ND	16MB SRAM (1Mx16)	16M-Bit SRAM (1Mx16)	48-BGA	16.50 15.40 14.30
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串行 EEPROM

微芯片技术

AC812001-ND	PICSEEM™ 介绍设计套件	PICSEEM™ Introduction Design Kit	—	330.00 — —
DV243002-ND	SEEPROM 设计员开发套件	SEEPROM Designer's Development Kit	—	99.99 — —
SEEPROM1-KIT-ND	Digi-Key® 低密度串行 EEPROM 套件	Digi-Key® Low-Density Serial EEPROM Kit	—	17.95 — —
SEEPROM2-KIT-ND	Digi-Key® 中密度串行 EEPROM 套件	Digi-Key® Mid-Density Serial EEPROM Kit	—	17.95 — —
SEEPROM3-KIT-ND	Digi-Key® 高密度串行 EEPROM 套件	Digi-Key® High-Density Serial EEPROM Kit	—	19.95 — —
SEEPROM4-KIT-ND	Digi-Key® 组合密度串行 EEPROM 套件	Digi-Key® Combo-Density Serial EEPROM Kit	—	29.95 — —

2 线接口

24AA00-I/P-ND	16x8 I²C 串行 EEPROM 1.8V	16x8 I²C Serial EEPROM 1.8V	8-Dip	.38 .21 .20
24AA00-I/SN-ND	16x8 I²C 串行 EEPROM 1.8V	16x8 I²C Serial EEPROM 1.8V	8-SOIC	.35 .20 .19
24AA00-I/ST-ND	16x8 I²C 串行 EEPROM 1.8V	16x8 I²C Serial EEPROM 1.8V	8-TSSOP	.43 .23 .22
24AA00T-I/OTCT-ND	16x8 I²C 串行 EEPROM 1.8V	16x8 I²C Serial EEPROM 1.8V	SOT-23-5	.39 .35 .32
24AA00T-I/OTTR-ND	16x8 I²C 串行 EEPROM 1.8V	16x8 I²C Serial EEPROM 1.8V	SOT-23-5	570.00/3,000
24LC00-I/P-ND	16x8 I²C 串行 EEPROM 2.5V	16x8 I²C Serial EEPROM 2.5V	8-Dip	.38 .21 .20
24LC00-I/SN-ND	16x8 I²C 串行 EEPROM 2.5V	16x8 I²C Serial EEPROM 2.5V	8-SOIC	.35 .20 .19
24LC00-I/P-ND	16x8 I²C 串行 EEPROM, 工业级温度, 2.5V	16x8 I²C Serial EEPROM, Ind. Temp. 2.5V	8-Dip	.38 .21 .20
24LC00-I/SN-ND	16x8 I²C 串行 EEPROM, 工业级温度, 2.5V	16x8 I²C Serial EEPROM, Ind. Temp. 2.5V	8-SOIC	.35 .20 .19
24LC00-I/ST-ND	16x8 I²C 串行 EEPROM, 工业级温度, 2.5V	16x8 I²C Serial EEPROM, Ind. Temp. 2.5V	8-TSSOP	.43 .23 .22
24LC00T-I/MCCT-ND	16x8 I²C 串行 EEPROM, 工业级温度, 2.5V	16x8 I²C Serial EEPROM, Ind. Temp. 2.5V	8-DFN	.56 .50 .45
24LC00T-I/MCTR-ND	16x8 I²C 串行 EEPROM, 工业级温度, 2.5V	16x8 I²C Serial EEPROM, Ind. Temp. 2.5V	8-DFN	858.00/3,300
24LC00T-I/OTCT-ND	16x8 I²C 串行 EEPROM, 工业级温度, 2.5V	16x8 I²C Serial EEPROM, Ind. Temp. 2.5V	SOT-23-5	.39 .35 .32
24LC00T-I/OTTR-ND	16x8 I²C 串行 EEPROM, 工业级温度, 2.5V	16x8 I²C Serial EEPROM, Ind. Temp. 2.5V	SOT-23-5	570.00/3,000
24C00-I/P-ND	16x8 I²C 串行 EEPROM 5V	16x8 I²C Serial EEPROM 5V	8-Dip	.38 .21 .20
24C00-I/P-ND	16x8 I²C 串行 EEPROM, 工业级温度, 5V	16x8 I²C Serial EEPROM, Ind. Temp. 5V	8-Dip	.38 .21 .20
24C00-I/SN-ND	16x8 I²C 串行 EEPROM, 工业级温度, 5V	16x8 I²C Serial EEPROM, Ind. Temp. 5V	8-SOIC	.35 .20 .19
24C00-I/ST-ND	16x8 I²C 串行 EEPROM, 工业级温度, 5V	16x8 I²C Serial EEPROM, Ind. Temp. 5V	8-TSSOP	.43 .23 .22
24C00T-I/MCCT-ND	16x8 I²C 串行 EEPROM, 工业级温度, 5V	16x8 I²C Serial EEPROM, Ind. Temp. 5V	8-DFN	.56 .50 .45
24C00T-I/MCTR-ND	16x8 I²C 串行 EEPROM, 工业级温度, 5V	16x8 I²C Serial EEPROM, Ind. Temp. 5V	8-DFN	858.00/3,300
24C00T-I/OTCT-ND	16x8 I²C 串行 EEPROM, 工业级温度, 5V	16x8 I²C Serial EEPROM, Ind. Temp. 5V	SOT-23-5	.39 .35 .32
24C00T-I/OTTR-ND	16x8 I²C 串行 EEPROM, 工业级温度, 5V	16x8 I²C Serial EEPROM, Ind. Temp. 5V	SOT-23-5	570.00/3,000
24AA01-I/MS-ND	1K (128x8) I²C 串行 EEPROM, 工业级温度, 1.8V	1K (128x8) I²C Serial EEPROM, Ind. Temp. 1.8V	8-MSOP	.45 .25 .24
24AA01-I/P-ND	1K (128x8) I²C 串行 EEPROM, 工业级温度, 1.8V	1K (128x8) I²C Serial EEPROM, Ind. Temp. 1.8V	8-Dip	.43 .23 .22
24AA01-I/SN-ND	1K (128x8) I²C 串行 EEPROM, 工业级温度, 1.8V	1K (128x8) I²C Serial EEPROM, Ind. Temp. 1.8V	8-SOIC	.38 .21 .20
24AA01-I/ST-ND	1K (128x8) I²C 串行 EEPROM, 工业级温度, 1.8V	1K (128x8) I²C Serial EEPROM, Ind. Temp. 1.8V	8-TSSOP	.45 .25 .24
24AA01T-I/OTCT-ND	1K (128x8) I²C 串行 EEPROM, 工业级温度, 1.8V	1K (128x8) I²C Serial EEPROM, Ind. Temp. 1.8V	SOT-23-5	.42 .38 .34
24AA01T-I/OTTR-ND	1K (128x8) I²C 串行 EEPROM, 工业级温度, 1.8V	1K (128x8) I²C Serial EEPROM, Ind. Temp. 1.8V	SOT-23-5	600.00/3,000
24LC01B-I/P-ND	1K (128x8) I²C 串行 EEPROM, 2.5V	1K (128x8) I²C Serial EEPROM 2.5V	8-Dip	.43 .23 .22
24LC01B-I/SN-ND	1K (128x8) I²C 串行 EEPROM, 工业级温度, 2.5V	1K (128x8) I²C Serial EEPROM, Ind. Temp. 2.5V	8-SOIC	.38 .21 .20
24LC01B-I/MS-ND	1K (128x8) I²C 串行 EEPROM, 工业级温度, 2.5V	1K (128x8) I²C Serial EEPROM, Ind. Temp. 2.5V	8-MSOP	.45 .25 .24
24LC01B-I/P-ND	1K (128x8) I²C 串行 EEPROM, 工业级温度, 2.5V	1K (128x8) I²C Serial EEPROM, Ind. Temp. 2.5V	8-Dip	.43 .23 .22
24LC01B-I/SN-ND	1K (128x8) I²C 串行 EEPROM, 工业级温度, 2.5V	1K (128x8) I²C Serial EEPROM, Ind. Temp. 2.5V	8-SOIC	.38 .21 .20
24LC01B-I/ST-ND	1K (128x8) I²C 串行 EEPROM, 工业级温度, 2.5V	1K (128x8) I²C Serial EEPROM, Ind. Temp. 2.5V	8-TSSOP	.45 .25 .24
24LC01B-T/MCCT-ND	1K (128x8) I²C 串行 EEPROM, 工业级温度, 2.5V	1K (128x8) I²C Serial EEPROM, Ind. Temp. 2.5V	8-DFN	.59 .53 .48
24LC01B-T/MCTR-ND	1K (128x8) I²C 串行 EEPROM, 工业级温度, 2.5V	1K (128x8) I²C Serial EEPROM, Ind. Temp. 2.5V	8-DFN	924.00/3,300
24LC01B-T/OTCT-ND	1K (128x8) I²C 串行 EEPROM, 工业级温度, 2.5V	1K (128x8) I²C Serial EEPROM, Ind. Temp. 2.5V	SOT-23-5	.42 .38 .34
24LC01B-T/OTTR-ND	1K (128x8) I²C 串行 EEPROM, 工业级温度, 2.5V	1K (128x8) I²C Serial EEPROM, Ind. Temp. 2.5V	SOT-23-5	600.00/3,000
24LC01B-T/SNCT-ND	1K (128x8) I²C 串行 EEPROM, 工业级温度, 2.5V	1K (128x8) I²C Serial EEPROM, Ind. Temp. 2.5V	8-SOIC	.42 .38 .34
24LC01B-T/SNTR-ND	1K (128x8) I²C 串行 EEPROM, 工业级温度, 2.5V	1K (128x8) I²C Serial EEPROM, Ind. Temp. 2.5V	8-SOIC	660.00/3,300
24C01C-I/P-ND	1K (128x8) I²C 串行 EEPROM, 5V (快速字节写入)	1K (128x8) I²C Serial EEPROM 5V (fast byte write)	8-Dip	.53 .29 .28
24C01C-I/SN-ND	1K (128x8) I²C 串行 EEPROM, 5V (快速字节写入)	1K (128x8) I²C Serial EEPROM 5V (fast byte write)	8-SOIC	.50 .27 .26
24C01C-I/MS-ND	1K (128x8) I²C 串行 EEPROM, 工业级温度, 5V	1K (128x8) I²C Serial EEPROM, Ind. Temp. 5V	8-MSOP	.55 .31 .30
24C01C-I/P-ND	1K (128x8) I²C 串行 EEPROM, 工业级温度, 5V	1K (128x8) I²C Serial EEPROM, Ind. Temp. 5V	8-Dip	.53 .29 .28
24C01C-I/SN-ND	1K (128x8) I²C 串行 EEPROM, 工业级温度, 5V	1K (128x8) I²C Serial EEPROM, Ind. Temp. 5V	8-SOIC	.50 .27 .26
24C01C-I/ST-ND	1K (128x8) I²C 串行 EEPROM, 工业级温度, 5V	1K (128x8) I²C Serial EEPROM, Ind. Temp. 5V	8-TSSOP	.55 .31 .30
24C01CT-I/MCCT-ND	1K (128x8) I²C 串行 EEPROM, 工业级温度, 5V	1K (128x8) I²C Serial EEPROM, Ind. Temp. 5V	8-DFN	.70 .63 .57
24C01CT-I/MCTR-ND	1K (128x8) I²C 串行 EEPROM, 工业级温度, 5V	1K (128x8) I²C Serial EEPROM, Ind. Temp. 5V	8-DFN	1089.00/3,300
24AA02-I/MS-ND	2K (256x8) I²C 串行 EEPROM, 工业级温度, 1.8V	2K (256x8) I²C Serial EEPROM, Ind. Temp. 1.8V	8-MSOP	.50 .27 .26
24AA02-I/P-ND	2K (256x8) I²C 串行 EEPROM, 工业级温度, 1.8V	2K (256x8) I²C Serial EEPROM, Ind. Temp. 1.8V	8-Dip	.45 .25 .24
24AA02-I/SN-ND	2K (256x8) I²C 串行 EEPROM, 工业级温度, 1.8V	2K (256x8) I²C Serial EEPROM, Ind. Temp. 1.8V	8-SOIC	.43 .23 .22
24AA02-I/ST-ND	2K (256x8) I²C 串行 EEPROM, 工业级温度, 1.8V	2K (256x8) I²C Serial EEPROM, Ind. Temp. 1.8V	8-TSSOP	.50 .27 .26
24AA02T-I/OTCT-ND	2K (256x8) I²C 串行 EEPROM, 工业级温度, 1.8V	2K (256x8) I²C Serial EEPROM, Ind. Temp. 1.8V	SOT-23-5	.48 .43 .39
24AA02T-I/OTTR-ND	2K (256x8) I²C 串行 EEPROM, 工业级温度, 1.8V	2K (256x8) I²C Serial EEPROM, Ind. Temp. 1.8V	SOT-23-5	660.00/3,000
24AA02ST-I/MCCT-ND	2K (256x8) I²C 串行 EEPROM, 工业级温度, 1.8V	2K (256x8) I²C Serial EEPROM, Ind. Temp. 1.8V	8-DFN	.84 .77 .73
24AA02ST-I/MCTR-ND	2K (256x8) I²C 串行 EEPROM, 工业级温度, 1.8V	2K (256x8) I²C Serial EEPROM, Ind. Temp. 1.8V	8-DFN	1221.00/3,300
24LCS52T-I/MCCT-ND	2K (256x8) I²C 串行 EEPROM, 工业级温度, 2.2V	2K (256x8) I²C Serial EEPROM, Ind. Temp. 2.2V	8-DFN	.78 .70 .63
24LCS52T-I/MCTR-ND	2K (256x8) I²C 串行 EEPROM, 工业级温度, 2.2V	2K (256x8) I²C Serial EEPROM, Ind. Temp. 2.2V	8-DFN	1221.00/3,300

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